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1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{DS}	Drain-source voltage (V _{GS} = 0)	55	V
V _{GS}	Gate- source voltage	±20	V
I _D ⁽¹⁾	Drain current (continuos) at T _C = 25 °C	80	Α
I _D ⁽¹⁾	Drain current (continuos) at T _C = 100 °C	80	Α
I _{DM} ⁽²⁾	Drain current (pulsed)	320	Α
P _{TOT}	Total dissipation at T _C = 25 °C	300	W
	Derating factor	2	W/°C
T _j T _{stg}	Operating junction temperature Storage temperature	-55 to 175	°C

^{1.} Current limited package

Table 3. Thermal resistance

Symbol	Parameter		Unit		
Symbol	raiametei	D ² PAK	TO-220	TO-247	Oilit
R _{thj-case}	Thermal resistance junction-case max		0.5		°C/W
R _{thj-amb}	Thermal resistance junction-ambient max	35 ⁽¹⁾	62.5	50	°C/W
T _I	Maximum lead temperature for soldering purpose	300			°C

^{1.} When mounted on 1 inch² FR-4 board, 2 oz Cu

Table 4. Avalanche characteristics

Symbol	Parameter	Max value	Unit
I _{AR}	Avalanche current, repetitive or not-repetitive (pulse width limited by T_j max)	40	А
E _{AS}	Single pulse avalanche energy (starting $T_j = 25$ °C, $I_D = I_{AR}$, $V_{DD} = 30$ V)	1000	mJ

^{2.} Pulse width limited by safe operating area

2 Electrical characteristics

(T_{CASE} = 25 °C unless otherwise specified)

Table 5. On/off states

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _{(BR)DSS}	Drain-source breakdown voltage	$I_D = 250 \ \mu A, \ V_{GS} = 0$	55			V
I _{DSS}	Zero gate voltage drain current (V _{GS} = 0)	V_{DS} = max rating V_{DS} = max rating@125 °C			1 10	μ Α μ Α
I _{GSS}	Gate body leakage current (V _{DS} = 0)	V _{GS} = ±20 V			±100	nA
V _{GS(th)}	Gate threshold voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2	3	4	٧
R _{DS(on)}	Static drain-source on resistance	V _{GS} = 10 V, I _D = 40 A		0.0065	0.008	Ω

Table 6. Dynamic

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
g _{fs} (1)	Forward transconductance	V _{DS} =15 V , I _D = 18 A		40		S
C _{iss} C _{oss} C _{rss}	Input capacitance Output capacitance Reverse transfer capacitance	$V_{DS} = 25 \text{ V, f} = 1 \text{ MHz,}$ $V_{GS} = 0$		3740 830 265		pF pF pF
Q _g Q _{gs} Q _{gd}	Total gate charge Gate-source charge Gate-drain charge	V_{DD} = 27 V, I_D = 80 A V_{GS} =10 V (see Figure 14)		112 20 40	155	nC nC nC

^{1.} Pulsed: pulse duration=300 µs, duty cycle 1.5%

Table 7. Switching times

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
$t_{ m d(on)} \ t_{ m r} \ t_{ m d(off)} \ t_{ m f}$	Turn-on delay time Rise time Turn-off-delay time Fall time	$V_{DD} = 27 \text{ V}, I_D = 40 \text{ A}$ $R_G = 4.7 \Omega V_{GS} = 10 \text{ V}$ (see Figure 13)		20 110 75 35		ns ns ns ns

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Table 8. Source drain diode

Symbol	Parameter	Test conditions	Min	Тур.	Max	Unit
I _{SD}	Source-drain current				80	Α
I _{SDM} ⁽¹⁾	Source-drain current (pulsed)				320	Α
V_{SD}	Forward on voltage	$I_{SD} = 80 \text{ A}, V_{GS} = 0$			1.5	V
t _{rr} ⁽²⁾ Q _{rr} I _{RRM}	Reverse recovery time Reverse recovery charge Reverse recovery current	$I_{SD} = 80 \text{ A}, V_{DD} = 25 \text{ V}$ di/dt=100 A/ μ s, $T_j = 150 ^{\circ}\text{C}$ (see Figure 18)		80 230 5.7		ns nC A

^{1.} Pulse width limited by safe operating area

^{2.} Pulsed: pulse duration = $300\mu s$, duty cycle 1.5%

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Figure 3. Thermal impedance

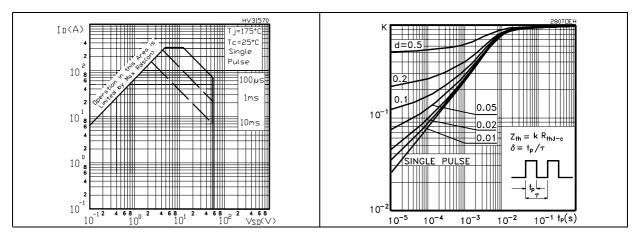


Figure 4. Output characteristics

Figure 5. Transfer characteristics

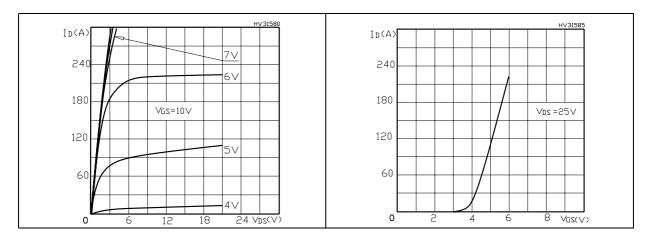
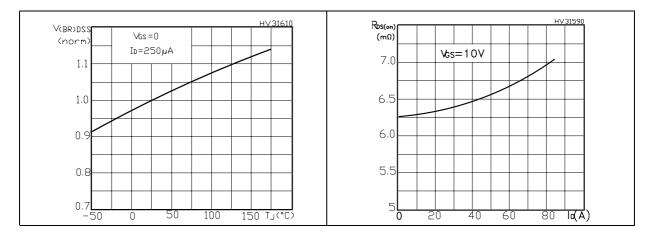


Figure 6. Normalized BV_{DSS} vs temperature Figure 7. Static drain-source on resistance



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Figure 8. Gate charge vs gate-source voltage Figure 9. Capacitance variations

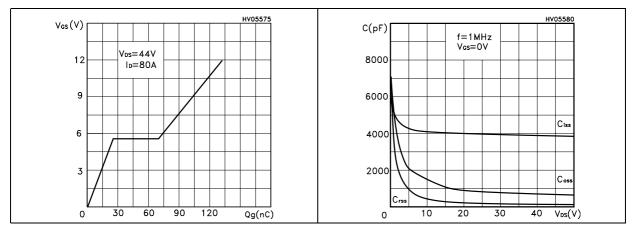


Figure 10. Normalized gate threshold voltage Figure 11. Normalized on resistance vs vs temperature temperature

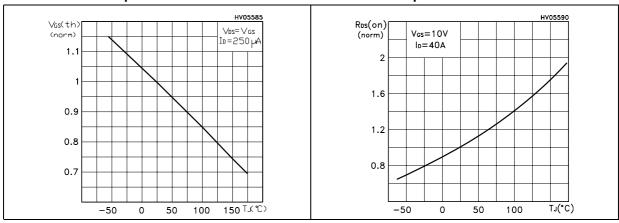
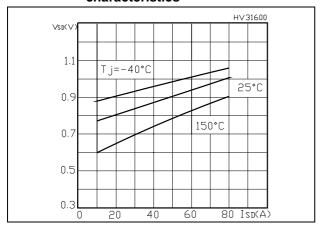


Figure 12. Source-drain diode forward characteristics



3 Test circuits

Figure 13. Switching times test circuit for resistive load

Figure 14. Gate charge test circuit

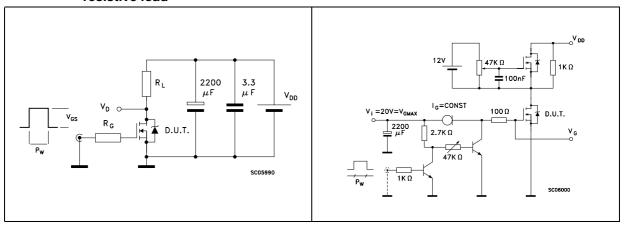


Figure 15. Test circuit for inductive load switching and diode recovery times

Figure 16. Unclamped inductive load test circuit

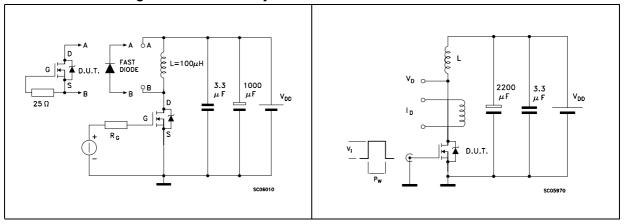
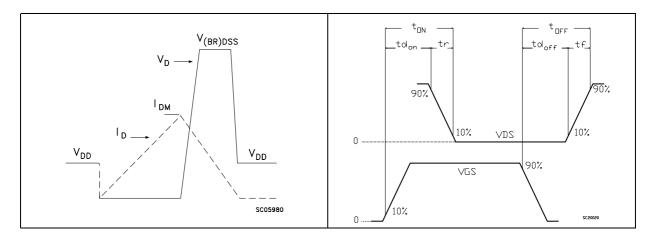


Figure 17. Unclamped inductive waveform

Figure 18. Switching time waveform



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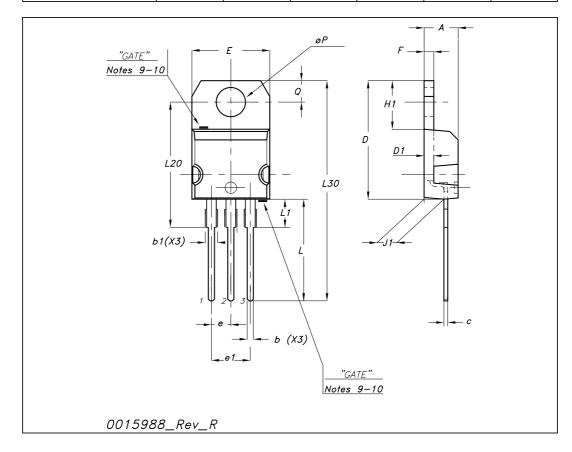
4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.



TO-220 mechanical data

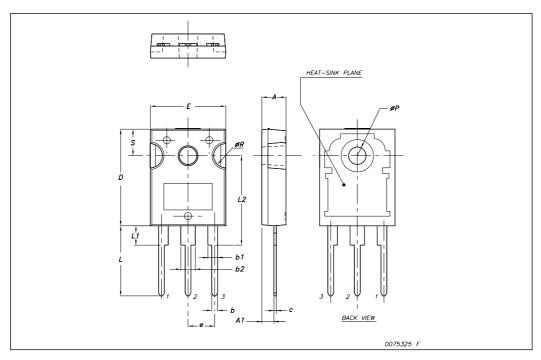
Di		mm		inch		
Dim	Min	Тур	Max	Min	Тур	Max
Α	4.40		4.60	0.173		0.181
b	0.61		0.88	0.024		0.034
b1	1.14		1.70	0.044		0.066
С	0.48		0.70	0.019		0.027
D	15.25		15.75	0.6		0.62
D1		1.27			0.050	
E	10		10.40	0.393		0.409
е	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
F	1.23		1.32	0.048		0.051
H1	6.20		6.60	0.244		0.256
J1	2.40		2.72	0.094		0.107
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L20		16.40			0.645	
L30		28.90			1.137	
ØP	3.75		3.85	0.147		0.151
Q	2.65		2.95	0.104		0.116



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TO-247	Mechanical	data
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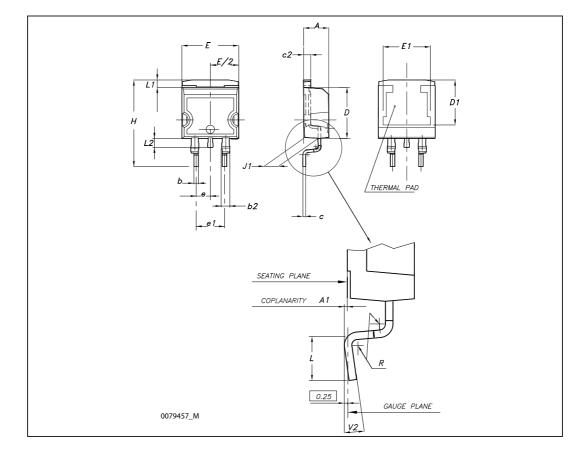
Dim.		mm.	
Diiii.	Min.	Тур	Max.
Α	4.85		5.15
A1	2.20		2.60
b	1.0		1.40
b1	2.0		2.40
b2	3.0		3.40
С	0.40		0.80
D	19.85		20.15
Е	15.45		15.75
е		5.45	
L	14.20		14.80
L1	3.70		4.30
L2		18.50	
øΡ	3.55		3.65
øR	4.50		5.50
S		5.50	



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D²PAK (TO-263) mechanical data

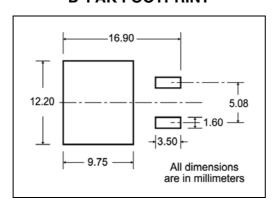
Dim		mm			inch	
Dim	Min	Тур	Max	Min	Тур	Max
Α	4.40		4.60	0.173		0.181
A1	0.03		0.23	0.001		0.009
b	0.70		0.93	0.027		0.037
b2	1.14		1.70	0.045		0.067
С	0.45		0.60	0.017		0.024
c2	1.23		1.36	0.048		0.053
D	8.95		9.35	0.352		0.368
D1	7.50			0.295		
E	10		10.40	0.394		0.409
E1	8.50			0.334		
е		2.54			0.1	
e1	4.88		5.28	0.192		0.208
Н	15		15.85	0.590		0.624
J1	2.49		2.69	0.099		0.106
L	2.29		2.79	0.090		0.110
L1	1.27		1.40	0.05		0.055
L2	1.30		1.75	0.051		0.069
R		0.4			0.016	
V2	0°		8°	0°		8°



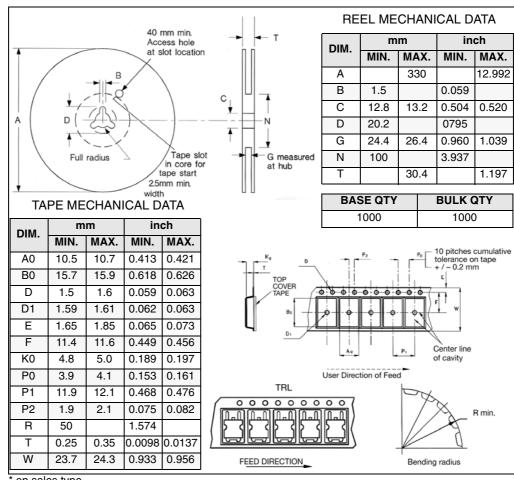
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Packaging mechanical data 5

D²PAK FOOTPRINT



TAPE AND REEL SHIPMENT



on sales type

6 Revision history

Table 9. Document revision history

Date	Revision	Changes
03-Mar-2008	1	First release
15-Apr-2009	2	Table 1: Device summary has been updated

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